Chip Monolithic Ceramic Capacitors



High Frequency GQM Series

Features

- 1. HiQ and low ESR at VHF, UHF, Microwave
- Feature improvement, low power consumption for mobile telecommunication. (Base station, terminal, etc.)

Applications

High frequency circuit (Mobile telecommunication, etc.)





Dart Number		Dimensions (mm)							
Part Number	L	W	Т	е	g min.				
GQM187	1.6±0.15	0.8±0.15	0.7 ±0.1	0.2 to 0.5	0.5				
GQM188	1.6±0.1	0.8±0.1	0.8±0.1	0.2 to 0.5	0.5				
GQM219 (50,100V)	2.0±0.1	1.25 ±0.1	0.85±0.1	0.2 to 0.7	0.7				
GQM219 (250V)	2.0±0.15	1.25±0.15	0.85±0.15	0.2 to 0.7	0.7				
GQM22M	2.8±0.5	2.8±0.4	1.15±0.2	0.3 m in.	1.0				

Array GNM Series



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Capacitance Table

Temperature Compensating Type COG (5C) Characteristics

7 ex.7: T Dimension [mm]

		1.6x0.8	3	2	.0x1.2	5	2.0x2.5
[mm]		(18) <0603:	>		(21) <0805:	>	<pre>(22) <0810></pre>
Rated Voltage	250	100	50	250	100	50	500
Capacitance [Vdc]	(2E)	(2A)	(1H)	(2E)	(2A)	(1H)	(2H)
0.10pF(R10)	7			1			
0.20pF(R20)	7			 			
0.30pF(R30)	7						
0.40pF(R40)	7						
0.50pF(R50)	7	8		9	9		м
0.75pF(R75)	7	8		9	9		М
1.0pF(1R0)	7	8		9	9		М
1.1pF(1R1)	7	8		9	9		М
1.2pF(1R2)	7	8		9	9		М
1.3pF(1R3)	7	8		9	9		М
1.5pF(1R5)	7	8		9	9		М
1.6pF(1R6)	7	8		9	9		М
1.8pF(1R8)	7	8		9	9		М
2.0pF(2R0)	7	8		9	9		М
2.2pF(2R2)	7	8		9	9		М
2.4pF(2R4)	7	8		9	9		М
2.7pF(2R7)	7	8		9	9		М
3.0pF(3R0)	7	8		9	9		М
3.3pF(3R3)	7	8		9	9		М
3.6pF(3R6)	7	8		9	9		М
3.9pF(3R9)	7	8		9	9		М
4.0pF(4R0)	7	8		9	9		М
4.3pF(4R3)	7	8		9	9		М
4.7pF(4R7)	7	8		9	9		м
5.0pF(5R0)	7	8		9	9		М
5.1pF(5R1)	7	8		9	9		м
5.6pF(5R6)	7	8	1	9	9		м
6.0pF(6R0)	7	8		9	9		м
6.2pF(6R2)	7	8		9	9		м
6.8pF(6R8)	7	8		9	9		м
7.0pF(7R0)	7		8	9	9		м
7.5pF(7R5)	7		8	9	9		м
8.0pF(8R0)	7		8	9	9		М
8.2pF(8R2)	7		8	9	9	1	М
9.0pF(9R0)	7		8	9	9		М
9.1pF(9R1)	7		8	9	9		м
10pF(100)	7		8	9	9	+	М
11pF(110)	7	1	8	9	9	1	М
12pF(120)	7		8	9	9		м
13pF(130)	7		8	9	9	1	М
15pF(150)	7		8	9	9		м
16pF(160)	7		8	9	9		М
18pF(180)	7		8	9	9		М
20pF(200)	7		8	9		9	м
22pF(220)	7		8	9		9	м
24pF(240)	7		8	9		9	м
27pF(270)	7		8	9		9	м
30pF(300)	7		8	9		9	М
33pF(330)	7		8	9		9	м

LxW [mm]		1.6x0.8 (18) <0603>	3	2	0x1.2 (21) <0805>	5	2.0x2.5 (22) <0810>	For General GRM Series
Rated Voltage	250	100	50	250	100	50	500	
Capacitance [Vdc]	(2E)	(2A)	(1H)	(2E)	(2A)	(1H)	(2H)	
36pF(360)	7		8	9		9	М	ies
39pF(390)	7		8	9		9	м	Ser
43pF(430)	7		8	9		9	м	ΙĀ
47pF(470)	7		8	9		9	м	ษ
51pF(510)		-	8	9		9	м	
56pF(560)			8	9		9	м	
62pF(620)			8	9		9	м	
68pF(680)			8	9		9	м	S.
75pF(750)			8	9		9	м	ESL
82pF(820)			8	9		9	м	N S
91pF(910)			8	9		9	м	ĽĽ
100pF(101)			8	9		9	М	

High-Q GJMSeries

> High Frequency GQM Series

Monolithic Mcrochip GMA Series

For Bonding GMD Series

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

muRata

al SS	Tempera	ture Com	pensating Type C	UG(5C) Character
erie				
ΞŠ	LxVV [mm]		1.6x0.8(1	8)<0603>
For GR	Rated Volt. [Vdc]	250 (2E)	100(2A)
	Capacitance	Tolerance	Part N	umber
	0.10pF(R10)	±0.1pF(B)	GQM1875C2ER10BB12D	
	0.20p F (R20)	±0.1p F (B)	GQM1875C2ER20BB12D	
	0. 30p F (R30)	±0.1p F (B)	GQM1875C2ER30BB12D	
/ ries		±0.25p F (C)	GQM1875C2ER30CB12D	
rra) 1Se	0.40p F (R40)	±0.1pF (B)	GQM1875C2ER40BB12D	
A 5		±0.25p F (C)	GQM1875C2ER40CB12D	
G	0.50p F (R50)	±0.1p F (B)	GQM1875C2ER50BB12D	GQM1885C2AR50BB01D
		±0.25p F (C)	GQM1875C2ER50CB12D	GQM1885C2AR50CB01D
	0.75p F (R75)	±0.1pF (B)	GQM1875C2ER75BB12D	GQM1885C2AR75BB01D
		±0.25p F (C)	GQM1875C2ER75CB12D	GQM1885C2AR75CB01D
es –	1. Ор F (1 R0)	±0.1p F (B)	GQM1875C2E1R0BB12D	GQM1885C2A1R0BB01D
ESI		±0.25p F (C)	GQM1875C2E1R0CB12D	GQM1885C2A1R0CB01D
8 □	1.1p F (1R1)	±0.1p F (B)	GQM1875C2E1R1BB12D	GQM1885C2A1R1BB01D
		±0.25p F (C)	GQM1875C2E1R1CB12D	GQM1885C2A1R1CB01D
	1. 2р F (1R2)	±0.1p F (B)	GQM1875C2E1R2BB12D	GQM1885C2A1R2BB01D
		±0.25p F (C)	GQM1875C2E1R2CB12D	GQM1885C2A1R2CB01D
	1. 3p F (1R3)	±0.1p F (B)	GQM1875C2E1R3BB12D	GQM1885C2A1R3BB01D
(0		±0.25p F (C)	GQM1875C2E1R3CB12D	GQM1885C2A1R3CB01D
Sries	1.5p F (1R5)	±0.1p F (B)	GQM1875C2E1R5BB12D	GQM1885C2A1R5BB01D
gh- 1Se		±0.25p F (C)	GQM1875C2E1R5CB12D	GQM1885C2A1R5CB01D
ΞΥ	1.6p F (1R6)	±0.1p F (B)	GQM1875C2E1R6BB12D	GQM1885C2A1R6BB01D
Ŭ		±0.25p F (C)	GQM1875C2E1R6CB12D	GQM1885C2A1R6CB01D
	1.8p F (1R8)	±0.1p F (B)	GQM1875C2E1R8BB12D	GQM1885C2A1R8BB01D
		±0.25p F (C)	GQM1875C2E1R8CB12D	GQM1885C2A1R8CB01D
y	2.0p F (2R0)	±0.1p F (B)	GQM1875C2E2R0BB12D	GQM1885C2A2R0BB01D
enc ies		±0.25p F (C)	GQM1875C2E2R0CB12D	GQM1885C2A2R0CB01D
equ	2.2p F (2R2)	±0.1p F (B)	GQM1875C2E2R2BB12D	GQM1885C2A2R2BB01D
QM QM		±0.25p F (C)	GQM1875C2E2R2CB12D	GQM1885C2A2R2CB01D
High G	2.4p F (2R4)	±0.1p F (B)	GQM1875C2E2R4BB12D	GQM1885C2A2R4BB01D
		±0.25p F (C)	GQM1875C2E2R4CB12D	GQM1885C2A2R4CB01D
	2.7p F (2R7)	±0.1p F (B)	GQM1875C2E2R7BB12D	GQM1885C2A2R7BB01D
j		±0.25p F (C)	GQM1875C2E2R7CB12D	GQM1885C2A2R7CB01D
ss	3. Op F (3R0)	±0.1p F (B)	GQM1875C2E3R0BB12D	GQM1885C2A3R0BB01D
Mc		±0.25p F (C)	GQM1875C2E3R0CB12D	GQM1885C2A3R0CB01D
A S	3. 3p F (3R3)	±0.1p F (B)	GQM1875C2E3R3BB12D	GQM1885C2A3R3BB01D
G⊽		±0.25p F (C)	GQM1875C2E3R3CB12D	GQM1885C2A3R3CB01D
/ou	3.6p F (3R6)	±0.1p F (B)	GQM1875C2E3R6BB12D	GQM1885C2A3R6BB01D
2		±0.25p F (C)	GQM1875C2E3R6CB12D	GQM1885C2A3R6CB01D
	3.9p F (3R9)	±0.1p F (B)	GQM1875C2E3R9BB12D	GQM1885C2A3R9BB01D
		±0.25p F (C)	GQM1875C2E3R9CB12D	GQM1885C2A3R9CB01D
dinç	4. Op F (4R0)	±0.1p F (B)	GQM1875C2E4R0BB12D	GQM1885C2A4R0BB01D
son Se		±0.25p F (C)	GQM1875C2E4R0CB12D	GQM1885C2A4R0CB01D
er E	4. 3p F (4R3)	±0.1p F (B)	GQM1875C2E4R3BB12D	GQM1885C2A4R3BB01D
щO		±0.25p F (C)	GQM1875C2E4R3CB12D	GQM1885C2A4R3CB01D
	4. 7p F (4R7)	±0.1p F (B)	GQM1875C2E4R7BB12D	GQM1885C2A4R7BB01D
		±0.25p F (C)	GQM1875C2E4R7CB12D	GQM1885C2A4R7CB01D
tion	5. Op F (5R0)	±0.1p F (B)	GQM1875C2E5R0BB12D	GQM1885C2A5R0BB01D
mai		±0.25p F (C)	GQM1875C2E5R0CB12D	GQM1885C2A5R0CB01D
-				

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

(Part Number) | **GQ** | **M** | 18 | 7 | 5**C** | 2**E** | **R10** | **B** | B12 D 0 0000 6 0 8 9 D

Product ID 2 Series 5 Temperature Characteristics 8Capacitance Tolerance

3Dimensions (LxW) 6 Rated Voltage Individual Specification Code

4Dimension (T) Capacitance Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

Product Information



LxW [mm]			1.6x0.8(18)<0603>	
Rated Volt. [Vdc]	250 (2E)	100 (2A)	50 (1H)
Capacitance	Tolerance		Part Number	
5.1p F (5R1)	±0.25p F (C)	GQM1875C2E5R1CB12D	GQM1885C2A5R1CB01D	
	±0.5p F (D)	GQM1875C2E5R1DB12D	GQM1885C2A5R1DB01D	
5.6p F (5R6)	±0.25p F (C)	GQM1875C2E5R6CB12D	GQM1885C2A5R6CB01D	
	±0.5p F (D)	GQM1875C2E5R6DB12D	GQM1885C2A5R6DB01D	
6. Op F (6R0)	±0.25p F (C)	GQM1875C2E6R0CB12D	GQM1885C2A6R0CB01D	
	±0.5p F (D)	GQM1875C2E6R0DB12D	GQM1885C2A6R0DB01D	
6. 2p F (6R2)	±0.25p F (C)	GQM1875C2E6R2CB12D	GQM1885C2A6R2CB01D	
	±0.5p F (D)	GQM1875C2E6R2DB12D	GQM1885C2A6R2DB01D	
6.8p F (6R8)	±0.25p F (C)	GQM1875C2E6R8CB12D	GQM1885C2A6R8CB01D	
	±0.5p F (D)	GQM1875C2E6R8DB12D	GQM1885C2A6R8DB01D	
7. Op F (7R0)	±0.25p F (C)	GQM1875C2E7R0CB12D		GQM1885C1H7R0CB01D
	±0.5p F (D)	GQM1875C2E7R0DB12D		GQM1885C1H7R0DB01D
7.5p F (7R5)	±0.25p F (C)	GQM1875C2E7R5CB12D		GQM1885C1H7R5CB01D
• • •	±0.5p F (D)	GQM1875C2E7R5DB12D		GQM1885C1H7R5DB01D
8. Op F (8R0)	±0.25p F (C)	GQM1875C2E8R0CB12D		GQM1885C1H8R0CB01D
	±0.5p F (D)	GQM1875C2E8R0DB12D		GQM1885C1H8R0DB01D
8.2p F (8R2)	±0.25p F (C)	GQM1875C2E8R2CB12D		GQM1885C1H8R2CB01D
	±0.5pF(D)	GQM1875C2E8R2DB12D		GQM1885C1H8R2DB01D
9. Op F (9R0)	±0.25p F (C)	GQM1875C2E9R0CB12D		GQM1885C1H9R0CB01D
	±0.50 F (D)	GQM1875C2E9R0DB12D		GQM1885C1H9R0DB01D
9.1pF(9R1)	±0.25p F (C)	GQM1875C2E9R1CB12D		GQM1885C1H9R1CB01D
- F (C)	+0.50 F (D)	GQM1875C2E9R1DB12D		GQM1885C1H9R1DB01D
100 F (100)	+2% (G)	GQM1875C2E100GB12D		GQM1885C1H100GB01D
	±5% (J)	GQM1875C2E100JB12D		GQM1885C1H100JB01D
11p F (110)	+2% (G)	GQM1875C2E110GB12D		GQM1885C1H110GB01D
	±5% (J)	GQM1875C2E110JB12D		GQM1885C1H110JB01D
12p F (120)	+2% (G)	GQM1875C2E120GB12D		GQM1885C1H120GB01D
	±5% (J)	GQM1875C2E120JB12D		GQM1885C1H120JB01D
1.3p F (130)	+2% (G)	GQM1875C2E130GB12D		GQM1885C1H130GB01D
	±5% (J)	GQM1875C2E130JB12D		GQM1885C1H130JB01D
15n F (150)	+2% (G)	GQM1875C2E150GB12D		GQM1885C1H150GB01D
ispi (100)	+5% (J)	GQM1875C2E150JB12D		GQM1885C1H150JB01D
16n F (160)	±2% (G)	GQM1875C2E160GB12D		GQM1885C1H160GB01D
·	±5% (J)	GQM1875C2E160JB12D		GQM1885C1H160JB01D
18n F (180)	+2% (G)	GQM1875C2E180GB12D		GQM1885C1H180GB01D
iqi (100)	+5% (1)	GQM1875C2E180.IB12D		GQM1885C1H180.JB01D
20n F (200)	+2% (G)	GQM1875C2E200GB12D		GQM1885C1H200GB01D
2001 (200)	+5% (1)	GOM1875C2E2000B12D		GOM1885C1H200 IB01D
22n F (220)	+2% (G)	GOM1875C2E220GB12D		GOM1885C1H220GB01D
22p (220)	+5% (1)	GOM1875C2E2203B12D		GOM1885C1H220JB01D
2∕In F (2∕I∩)	+2% (G)	GOM1875C2E240GB12D		GOM1885C1H240GB01D
2-ημι (2-η υ)	+5% (1)	GOM1875C2E240GB12D		GOM1885C1H240 IR01D
27n E (970)	+2% (C)	GOM1875C2E270GB12D		GOM1885C1U270GB01D
2/pr(2/0)	+5% (1)	GOM1875C2E270GB12D		GOM1885C1U270 IB01D
30 E (200)	+2% (C)	GOM1875C2E200GB12D		GOM1885C1H300GB01D
504 F (300)	+5% (1)	COM1875C2E2000B12D		COM1885C1U200 ID04D
		Sam IOI JOZEJUUJD IZD		

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code



LxW [mm]		1.6x0.8(1	8)<0603>
Rated Volt. [Vdc]	250 (2E)	50 (1H)
Capacitance	Tolerance	Part N	umber
33p F (330)	±2% (G)	GQM1875C2E330GB12D	GQM1885C1H330GB01D
	±5% (J)	GQM1875C2E330JB12D	GQM1885C1H330JB01D
36p F (360)	±2% (G)	GQM1875C2E360GB12D	GQM1885C1H360GB01D
	±5% (J)	GQM1875C2E360JB12D	GQM1885C1H360JB01D
39p F (390)	±2% (G)	GQM1875C2E390GB12D	GQM1885C1H390GB01D
	±5% (J)	GQM1875C2E390JB12D	GQM1885C1H390JB01D
43p F (430)	±2% (G)	GQM1875C2E430GB12D	GQM1885C1H430GB01D
	±5% (J)	GQM1875C2E430JB12D	GQM1885C1H430JB01D
47p F (470)	±2% (G)	GQM1875C2E470GB12D	GQM1885C1H470GB01D
	±5% (J)	GQM1875C2E470JB12D	GQM1885C1H470JB01D
51p F (510)	±2% (G)		GQM1885C1H510GB01D
	±5% (J)		GQM1885C1H510JB01D
56p F (560)	±2% (G)		GQM1885C1H560GB01D
	±5% (J)		GQM1885C1H560JB01D
62p F (620)	±2% (G)		GQM1885C1H620GB01D
	±5% (J)		GQM1885C1H620JB01D
68p F (680)	±2% (G)		GQM1885C1H680GB01D
	±5% (J)		GQM1885C1H680JB01D
75p F (750)	±2% (G)		GQM1885C1H750GB01D
	±5% (J)		GQM1885C1H750JB01D
82p F (820)	±2% (G)		GQM1885C1H820GB01D
	±5% (J)		GQM1885C1H820JB01D
91p F (910)	±2% (G)		GQM1885C1H910GB01D
	±5% (J)		GQM1885C1H910JB01D
100p F (101)	±2% (G)		GQM1885C1H101GB01D
	±5% (J)		GQM1885C1H101JB01D

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

(Part Number) GQ M 18 7 5C 2E 330 G B12 D Q 3 4 5 6 9 3 9 0 Packaging Code in Part Number shows STD 180mm Reel Taping.

Product ID
Series
Temperature Characteristics
Capacitance Tolerance

Obimensions (LxW)
Rated Voltage
Individual Specification Code

Dimension (T)
Capacitance
Packaging

Array GNM Series

For Bonding GMD Series



LxW [mm]		2.0x 1.25	21)<0805>	2.8x2.8(22)<1111>
Rated Volt. [Vdc]	250 (2E)	100 (2A)	500 (2H)
Capacitance	Tolerance		Part Number	
0.50p F (R50)	±0.1p F (B)	GQM2195C2ER50BB12D	GQM2195C2AR50BB01D	GQM22M5C2HR50BB01L
	±0.25p F (C)	GQM2195C2ER50CB12D	GQM2195C2AR50CB01D	GQM22M5C2HR50CB01L
0.75p F (R75)	±0.1p F (B)	GQM2195C2ER75BB12D	GQM2195C2AR75BB01D	GQM22M5C2HR75BB01L
	±0.25p F (C)	GQM2195C2ER75CB12D	GQM2195C2AR75CB01D	GQM22M5C2HR75CB01L
1. Op F (1R0)	±0.1p F (B)	GQM2195C2E1R0BB12D	GQM2195C2A1R0BB01D	GQM22M5C2H1R0BB01L
	±0.25p F (C)	GQM2195C2E1R0CB12D	GQM2195C2A1R0CB01D	GQM22M5C2H1R0CB01L
1.1p F (1R1)	±0.1p F (B)	GQM2195C2E1R1BB12D	GQM2195C2A1R1BB01D	GQM22M5C2H1R1BB01L
• • •	±0.25p F (C)	GQM2195C2E1R1CB12D	GQM2195C2A1R1CB01D	GQM22M5C2H1R1CB01L
1.2pF(1R2)	±0.1p F (B)	GQM2195C2E1R2BB12D	GQM2195C2A1R2BB01D	GQM22M5C2H1R2BB01L
	±0.25p F (C)	GQM2195C2E1R2CB12D	GQM2195C2A1R2CB01D	GQM22M5C2H1R2CB01L
1.3p F (1R3)	±0.1p F (B)	GQM2195C2E1R3BB12D	GQM2195C2A1R3BB01D	GQM22M5C2H1R3BB01L
	±0.25p F (C)	GQM2195C2E1R3CB12D	GQM2195C2A1R3CB01D	GQM22M5C2H1R3CB01L
1.50 F (1R5)	±0.1p F (B)	GQM2195C2E1R5BB12D	GQM2195C2A1R5BB01D	GQM22M5C2H1R5BB01L
-r (-)	±0.250 F (C)	GQM2195C2E1R5CB12D	GQM2195C2A1R5CB01D	GQM22M5C2H1R5CB01L
1.60 F (1R6)	±0.1pF(B)	GQM2195C2E1R6BB12D	GQM2195C2A1R6BB01D	GQM22M5C2H1R6BB01L
	+0.250 F (C)	GQM2195C2E1R6CB12D	GQM2195C2A1R6CB01D	GQM22M5C2H1R6CB01L
1.80 F (1 R 8)	+0.1n F (B)	GQM2195C2E1R8BB12D	GQM2195C2A1R8BB01D	GQM22M5C2H1R8BB01L
	+0.25n F (C)	GQM2195C2F1R8CB12D	GOM2195C2A1R8CB01D	GOM22M5C2H1R8CB01I
2 Cn F (2R0)	+0.1n F (B)	GQM2195C2E2R0BB12D	GQM2195C2A2R0BB01D	GQM22M5C2H2R0BB01L
2.41 (210)	$\pm 0.25 n E(C)$	GOM2195C2E2R0BB12D	GOM2195C2A2R0CB01D	GOM22M5C2H2R0CB01L
2 2n E (2R2)	+0.1n F (B)	GOM2195C2E2R00B12D	GOM2195C2A2R2BB01D	GOM22M5C2H2R2BB01L
2.41 (2.12)	$\pm 0.25 n E(C)$	GOM2195C2E2R2BB12D	GOM2195C2A2R2CB01D	GOM22M5C2H2R2CB01L
2 <i>A</i> n F (2R4)	+0.1n F (B)	GOM2195C2E2R20B12D	GOM2195C2A2R4BB01D	GOM22M5C2H2R4BB01I
2pr (2. (+)	$\pm 0.25 n E(C)$	GOM2195C2E2R4BB12D	GOM2195C2A2R4CB01D	GOM22M5C2H2R4CB01L
2 7n F (2R7)	+0.1n F (B)	GQM2195C2E2R7BB12D	GQM2195C2A2R7BB01D	GQM22M5C2H2R7BB01L
2.701 (2107)	$\pm 0.25 n E(C)$	GOM2195C2E2R7CB12D	GOM2195C2A2R7CB01D	GOM22M5C2H2R7CB01L
3 Cn E (3 R 0)	+0.1n F (B)	GOM2195C2E3R0BB12D	GOM2195C2A3R0BB01D	GOM22M5C2H3R0BB01L
а.ф/ (бло)	$\pm 0.25 n E(C)$	GOM2195C2E3R0CB12D	GOM2195C2A3R0CB01D	GOM22M5C2H3R0CB01L
3.3n F (3 P 3)	+0.1n F (B)	GOM2195C2E3R3BB12D	GOM2195C2A3R3BB01D	GOM22M5C2H3R3BB01L
3.spr (010)	$\pm 0.25 n E(C)$	GOM2195C2E3R3CB12D	GOM2195C2A3R3CB01D	GOM22M5C2H3R3CB01L
3.6n.F.(3.P.6)	+0.1n F (B)	GOM2195C2E3R6BB12D	GOM2195C2A3R6BB01D	GOM22M5C2H3R6BB01L
3.cp1 (510)	$\pm 0.25 n E(C)$	GOM2195C2E3R6CB12D	GOM2195C2A3R6CB01D	GOM22M5C2H3R6CB01L
3 On F (3 P 0)	+0.1n F (B)	GOM2195C2E3R9BB12D	GOM2195C2A3R9BB01D	GOM22M5C2H3R9BB01L
a.spr (010)	$\pm 0.25 n E(C)$	GQM2195C2E3R9CB12D	GOM2195C2A3R9CB01D	GOM22M5C2H3R9CB01L
4 m E (4 P0)	+0.1n F (B)	GOM2195C2E4R0BB12D	GOM2195C2A4R0BB01D	GOM22M5C2H4R0BB01L
-τ.φr (+r.υ)	+0.25n F (C)	GOM2195C2E4R0CB12D	GOM2195C2A4R0CB01D	GOM22M5C2H4R0CB01
/ 3n F (/ P3)	+0.1n F (B)	GOM2195C2E4R3BB12D	GOM2195C2A4R3BB01D	GOM22M5C2H4R3BB01L
ч. ф1 (413)	+0.25n E(C)	GOM2195C2E4R3CB12D	GOM2195C2A4R3CB01D	GOM22M5C2H4R3CB01L
/ 7n F (/ P7)	+0.1n F (B)	GOM2195C2E4R7BB12D	GOM2195C2A4R7BB01D	GOM22M5C2H4R7BB01L
ч. /рт (чт.т)	+0.25n E(C)	GOM2195C2E4R7CB12D	GOM2195C2A4R7CB01D	GOM22M5C2H4R7CB01L
5 m F (5DA)	+()1n F/DE)	GOM2195C2E4R70B12D	GOM2195C2A5P0PP01D	GOM22M5C2H5R0BB011
ο.φr (σκυ)	+0.255 E(C)	GOM2105C2E5D0CB12D	GOM2105C2A5D0CB01D	GOM22M5C2H5R0CR01
5 1n F (6D1)	$\pm 0.23 \mu r (\mathbf{C})$ $\pm 0.25 \mu r (\mathbf{C})$	GOM2195C2E5P1CB12D	GOM2195C2A5P1CB01D	GQM22M5C2H5R1CB011
J. IPF (JRI)	⊥0.2-0µ୮(ບ) +05∞೯ / ∩0	GOM2105C2E5R10B12D	GOM2105C2A5R10B01D	GOM22M5C2H5R1DR011
5 60 E (EDE)	+0.25n E (P)	GOM2105C2ESRIDB12D	GOM2105C2A5RIDBUID	GOM22M5C2H5R6CB011
υ. φ r (υ κα)	±0.2-0µr(∪) +0.5∞r /∩)	GOM2105C2E5R00012D	GOM2105C2A5R0CD01D	GOM22M5C2H5R6DR011
	+0.25n E (P)	GOM2105C2E6D0CD12D	GOM2105C2ASRODDUID	GOM22M5C2H6R0CR011
	⊥0.2-0µr(∪) +0.5∞r (∩)	COM2105C2E0D0D012D	COM2105C2ACRUCUCDUID	GOM22M5C2H6D0DB01L
	⊥orch ⊾(nor)	COMIZ 1950ZEURUDD IZD	COMIZ 133CZAURUDDUTD	S G M Z Z M S O Z M O N O D O I L

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code



al es	Temperat	ture Com	pensating Type C	OG(5C) Character	istics	
Serie	LxW [mm]			2.0x1.25(21)<0805>		2.8x2.8(22)<1111>
Pr G	Rated Volt. [Vdc]	1	250(2E)	100(2A)	50(1H)	500 (2H)
щ	Capacitance	Tolerance		Part N	umber	
	6.2pF(6R2)	±0.25p F (C)	GQM2195C2E6R2CB12D	GQM2195C2A6R2CB01D		GQM22M5C2H6R2CB01L
		±0.50 F (D)	GQM2195C2E6R2DB12D	GQM2195C2A6R2DB01D		GQM22M5C2H6R2DB01L
	6.8pF(6R8)	±0.250 F (C)	GQM2195C2E6R8CB12D	GQM2195C2A6R8CB01D		GQM22M5C2H6R8CB01L
SS		+0.50 F (D)	GQM2195C2E6R8DB12D	GQM2195C2A6R8DB01D		GQM22M5C2H6R8DB01L
ay Serio	7.00 F (7R0)	±0.250 F (C)	GQM2195C2E7R0CB12D	GQM2195C2A7R0CB01D		GQM22M5C2H7R0CB01L
MS	-r × -7	+0.50 F (D)	GQM2195C2E7R0DB12D	GQM2195C2A7R0DB01D		GQM22M5C2H7R0DB01L
GN	7.5p F (7R5)	±0.25p F (C)	GQM2195C2E7R5CB12D	GQM2195C2A7R5CB01D		GQM22M5C2H7R5CB01L
		±0.5pF(D)	GQM2195C2E7R5DB12D	GQM2195C2A7R5DB01D		GQM22M5C2H7R5DB01L
	8.0p F (8R0)	±0.25p F (C)	GQM2195C2E8R0CB12D	GQM2195C2A8R0CB01D		GQM22M5C2H8R0CB01L
		±0.5pF(D)	GQM2195C2E8R0DB12D	GQM2195C2A8R0DB01D		GQM22M5C2H8R0DB01L
(0	8.2pF(8R2)	±0.25p F (C)	GQM2195C2E8R2CB12D	GQM2195C2A8R2CB01D		GQM22M5C2H8R2CB01L
SL		±0.5p F (D)	GQM2195C2E8R2DB12D	GQM2195C2A8R2DB01D		GQM22M5C2H8R2DB01L
Se	9. Op F (9R0)	±0.25p F (C)	GQM2195C2E9R0CB12D	GQM2195C2A9R0CB01D		GQM22M5C2H9R0CB01L
E E		±0.5p F (D)	GQM2195C2E9R0DB12D	GQM2195C2A9R0DB01D		GQM22M5C2H9R0DB01L
	9.1p F (9R1)	±0.25p F (C)	GQM2195C2E9R1CB12D	GQM2195C2A9R1CB01D		GQM22M5C2H9R1CB01L
		±0.5p F (D)	GQM2195C2E9R1DB12D	GQM2195C2A9R1DB01D		GQM22M5C2H9R1DB01L
	1 Op F (100)	±2% (G)	GQM2195C2E100GB12D	GQM2195C2A100GB01D		GQM22M5C2H100GB01L
	• • •	±5% (J)	GQM2195C2E100JB12D	GQM2195C2A100JB01D		GQM22M5C2H100JB01L
2 ries	11p F (110)	±2% (G)	GQM2195C2E110GB12D	GQM2195C2A110GB01D		GQM22M5C2H110GB01L
Jh-(• • •	±5% (J)	GQM2195C2E110JB12D	GQM2195C2A110JB01D		GQM22M5C2H110JB01L
ΞĚ	12p F (120)	±2% (G)	GQM2195C2E120GB12D	GQM2195C2A120GB01D		GQM22M5C2H120GB01L
9		±5% (J)	GQM2195C2E120JB12D	GQM2195C2A120JB01D		GQM22M5C2H120JB01L
	1 3p F (130)	±2% (G)	GQM2195C2E130GB12D	GQM2195C2A130GB01D		GQM22M5C2H130GB01L
		±5% (J)	GQM2195C2E130JB12D	GQM2195C2A130JB01D		GQM22M5C2H130JB01L
y	15p F (150)	±2% (G)	GQM2195C2E150GB12D	GQM2195C2A150GB01D		GQM22M5C2H150GB01L
enc		±5% (J)	GQM2195C2E150JB12D	GQM2195C2A150JB01D		GQM22M5C2H150JB01L
ser	16p F (160)	±2% (G)	GQM2195C2E160GB12D	GQM2195C2A160GB01D		GQM22M5C2H160GB01L
a Fre QM		±5% (J)	GQM2195C2E160JB12D	GQM2195C2A160JB01D		GQM22M5C2H160JB01L
High G(18p F (180)	±2% (G)	GQM2195C2E180GB12D	GQM2195C2A180GB01D		GQM22M5C2H180GB01L
<u> </u>		±5% (J)	GQM2195C2E180JB12D	GQM2195C2A180JB01D		GQM22M5C2H180JB01L
	20p F (200)	±2% (G)	GQM2195C2E200GB12D		GQM2195C1H200GB01D	GQM22M5C2H200GB01L
ih		±5% (J)	GQM2195C2E200JB12D		GQM2195C1H200JB01D	GQM22M5C2H200JB01L
ss	22p F (220)	±2% (G)	GQM2195C2E220GB12D		GQM2195C1H220GB01D	GQM22M5C2H220GB01L
Mc		±5% (J)	GQM2195C2E220JB12D		GQM2195C1H220JB01D	GQM22M5C2H220JB01L
A S	24p F (240)	±2% (G)	GQM2195C2E240GB12D		GQM2195C1H240GB01D	GQM22M5C2H240GB01L
GN GN		±5% (J)	GQM2195C2E240JB12D		GQM2195C1H240JB01D	GQM22M5C2H240JB01L
Von	27p F (270)	±2% (G)	GQM2195C2E270GB12D		GQM2195C1H270GB01D	GQM22M5C2H270GB01L
2		±5% (J)	GQM2195C2E270JB12D		GQM2195C1H270JB01D	GQM22M5C2H270JB01L
	3Op F (300)	±2% (G)	GQM2195C2E300GB12D		GQM2195C1H300GB01D	GQM22M5C2H300GB01L
o s		±5% (J)	GQM2195C2E300JB12D		GQM2195C1H300JB01D	GQM22M5C2H300JB01L
erie	ЗЗр F (330)	±2% (G)	GQM2195C2E330GB12D		GQM2195C1H330GB01D	GQM22M5C2H330GB01L
Bon D Se		±5% (J)	GQM2195C2E330JB12D		GQM2195C1H330JB01D	GQM22M5C2H330JB01L
GM	36p F (360)	±2% (G)	GQM2195C2E360GB12D		GQM2195C1H360GB01D	GQM22M5C2H360GB01L
щU		±5% (J)	GQM2195C2E360JB12D		GQM2195C1H360JB01D	GQM22M5C2H360JB01L
	39p F (390)	±2% (G)	GQM2195C2E390GB12D		GQM2195C1H390GB01D	GQM22M5C2H390GB01L
		±5% (J)	GQM2195C2E390JB12D		GQM2195C1H390JB01D	GQM22M5C2H390JB01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

(Part Number) | GQ | M | 21 | 9 | 5C | 2E | 6R2 | C | B12 | D O 0000 6 0 9 Ð 8

Product ID 2 Series 5 Temperature Characteristics 8Capacitance Tolerance

3Dimensions (LxW) 6 Rated Voltage Individual Specification Code

4 Dimension (T) Capacitance Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.



106



LxW [mm]		2.0x 1.25(21)<0805>	2.8x2.8(22)<1111>
Rated Volt. [Vdc]	250 (2E)	50 (1H)	500 (2H)
Capacitance	Tolerance		Part Number	
43p F (430)	±2% (G)	GQM2195C2E430GB12D	GQM2195C1H430GB01D	GQM22M5C2H430GB01L
	±5% (J)	GQM2195C2E430JB12D	GQM2195C1H430JB01D	GQM22M5C2H430JB01L
47p F (470)	±2% (G)	GQM2195C2E470GB12D	GQM2195C1H470GB01D	GQM22M5C2H470GB01L
	±5% (J)	GQM2195C2E470JB12D	GQM2195C1H470JB01D	GQM22M5C2H470JB01L
51p F (510)	±2% (G)	GQM2195C2E510GB12D	GQM2195C1H510GB01D	GQM22M5C2H510GB01L
	±5% (J)	GQM2195C2E510JB12D	GQM2195C1H510JB01D	GQM22M5C2H510JB01L
56p F (560)	±2% (G)	GQM2195C2E560GB12D	GQM2195C1H560GB01D	GQM22M5C2H560GB01L
	±5% (J)	GQM2195C2E560JB12D	GQM2195C1H560JB01D	GQM22M5C2H560JB01L
62p F (620)	±2% (G)	GQM2195C2E620GB12D	GQM2195C1H620GB01D	GQM22M5C2H620GB01L
	±5% (J)	GQM2195C2E620JB12D	GQM2195C1H620JB01D	GQM22M5C2H620JB01L
68p F (680)	±2% (G)	GQM2195C2E680GB12D	GQM2195C1H680GB01D	GQM22M5C2H680GB01L
	±5% (J)	GQM2195C2E680JB12D	GQM2195C1H680JB01D	GQM22M5C2H680JB01L
75p F (750)	±2% (G)	GQM2195C2E750GB12D	GQM2195C1H750GB01D	GQM22M5C2H750GB01L
	±5% (J)	GQM2195C2E750JB12D	GQM2195C1H750JB01D	GQM22M5C2H750JB01L
82p F (820)	±2% (G)	GQM2195C2E820GB12D	GQM2195C1H820GB01D	GQM22M5C2H820GB01L
	±5% (J)	GQM2195C2E820JB12D	GQM2195C1H820JB01D	GQM22M5C2H820JB01L
91p F (910)	±2% (G)	GQM2195C2E910GB12D	GQM2195C1H910GB01D	GQM22M5C2H910GB01L
	±5% (J)	GQM2195C2E910JB12D	GQM2195C1H910JB01D	GQM22M5C2H910JB01L
100p F (101)	±2% (G)	GQM2195C2E101GB12D	GQM2195C1H101GB01D	GQM22M5C2H101GB01L
	±5% (J)	GQM2195C2E101JB12D	GQM2195C1H101JB01D	GQM22M5C2H101JB01L

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code



GQM Series Specifications and Test Methods

<u> </u>								
MSe	No.	Ite	em	Specifications		Test Me	ethod	
GR	1	Operating Temperatu	ure	-55 to 125°C	Reference Tempera	ature: 25℃		
ries	2	Rated Vo	ltage	See the previous page.	The rated voltage is be applied continuc When AC voltage is whichever is larger, voltage range.	s defined as th pusly to the cap s superimpose should be ma	e maximum vo pacitor. d on DC voltag iintained within	ltage that may ge, V ^{p.p} or V ^{o.p} , the rated
Ser	3	Appearar	nce	No defects or abnormalities	Visual inspection			
ξ	4	Dimensio	n	Within the specified dimensions	Using calipers			
Ū	5	Dielectric	: Strength	No defects or abnormalities	No failure should be is applied between provided the charge *GQM187, GQM	e observed wh the termination e/discharge cu 219(250V), GC	en 300%* of th ns for 1 to 5 se rrent is less the M22: 250% of	ne rated voltage conds, an 50mA. the rated voltage
w ESE	6	Insulation	Resistance	More than 10,000MΩ	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 2 minutes of charging, provided the charge/discharge current is less than 50mA.			
3 🖵	7	Capacita	nce	Within the specified tolerance	The capacitance/Q	should be mea	asured at 25℃	at the
_				30pF and over: Q≧1400	frequency and volta	age shown in th	he table.	
	8	Q		30pF and below: Q≧800+20C	Frequency		1±0.1MHz	
				C: Nominal Capacitance (pF)	Voltage		0.5 to 5Vrms	3
			Tomporatura	· · · · · · · · · · · · · · · · · · ·	The canacitance ch	ange should h	e measured af	ter 5 min at
ries			Coefficient	Within the specified tolerance (Table A)	each specified temp	o. stage.		ter o min. at
GJMS	9	Capacitance Temperature Characteristics	Capacitance Drift	Within $\pm 0.2\%$ or ± 0.05 pF (whichever is larger)	measured in step 3 as a reference. When cycling the temperature sequentially from steps 1 through the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the steps 1, 3 and 5 by the capacitance value in step 3.			
ies					Step	T	emperature (C	:)
Ser					1	Ref	erence Temp.	±2
Ĭ					2	Def	-55±3	10
00 00					<u> </u>	Rei	125+3	±2
					5	Ref	erence Temp.	+2
GMA Series	10	Adhesive	Strength	No removal of the terminations or other defect should occur.	Solder the capacitor Fig. 1 using a eutect with the test jig for 1 The soldering shoul reflow method and s soldering is uniform	to the test jig (tic solder. Ther 0±1 sec. d be done eithe should be cond and free of def	glass epoxy bo a apply 10N* for er with an iron o lucted with care ects such as he	ard) shown in rce in parallel or using the so that the eat shock. *5N (GQM188)
		of lermin	nation		Type	а	b	С
					GQM18	1.0	3.0	1.2
				Solder resist	GQM21 GOM22	1.2	4.0	1.65
ies				Baked electrode or copper foil			0.0	(in mm)
Ser			Annearance	No defects or abnormalities	Solder the capacito	r to the test iid		noard) in the
			Capacitanco		same manner and u	under the same	e conditions as	s (10).
5	11	Vibration Resistance	Q	30pF and over: Q≥1400 30pF and below: Q≥800+20C	The capacitor shou having a total ampli uniformly between the frequency range, fre be traversed in app	Id be subjected itude of 1.5mm the approximation 10 to 55Hz roximately 1 m	d to a simple h n, the frequenc te limits of 10 a and return to ninute.	armonic motion y being varied and 55Hz. The 10Hz, should
				C. Nominal Capacitance (PF)	3 mutually perpend	be applied for icular direction	a period of 2 h is (total of 6 hc	ours in each of ours).

Continued on the following page.

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GQM Series Specifications and Test Methods

о.	Ite	em		Specific	ations			Tes	st Metho	d	
		Appearance Capacitance Change	No defects or abno Within $\pm 5\%$ or ± 0.3 (whichever is large	ormalities. 5pF er)			Solder the ca in Fig. 2 using Then apply a	pacitor on the t a eutectic solo force in the dire	est jig (gl der. ection sho	ass epoxy boar	rd) shown
12	Deflection	n	Туре		¢4.5	.6mm C	of defects suc	R230	50 Press	Idering is unifo surizing d: 1.0mm/sec. rize Flexure : ≤1	rm and free
			GQM18 GQM21	1.0	3.0	1.2		Capacitar	nce meter		
			GQM22	2.2	4.0 5.0	2.9		45	45	•	
				Fig.	2	(in mm)		Fig.	3		
13	Solderab Terminati	ility of ion	75% of the terminati and continuously.	tions are to be s	soldered evenly	,	Immerse the or rosin (JIS-K-5 80 to 120°C fo eutectic solde Sn-3.0Ag-0.5	capacitor in a s 902) (25% rosi r 10 to 30 secc r solution for 2 Cu solder solut	olution of in in weig onds. Afte ±0.5 sec ion for 2±	f ethanol (JIS-K ht proportion). In preheating, ir ponds at 230±5° ±0.5 seconds a	C-8101) and Preheat at mmerse in C or t 245±5°C.
			The measured and specifications in the	l observed cha e following tab	aracteristics sh lle.	ould satisfy the					
		Appearance	No defects or abno	ormalities.			_				
	Decister	Capacitance Change	Within ±2.5% or ± (whichever is large	:0.25 pF er)			Preheat the c	apacitor at 120	to 150℃	for 1 minute. Ir	mmerse the
4	Resistance to Soldering Heat	Q	30pF and over: Q≧ 30pF and below: Q	≧1400 2≧800+20C			capacitor in a at 270±5℃ fo 24±2 hours, t	eutectic solder r 10±0.5 secor hen measure.	or Sn-3. nds. Let s	0Ag-0.5Cu solo it at room temp	der solution berature for
			C: Nominal Capaci	itance (pF)			_				
		I.R.	More than 10,000M	MΩ			_				
		Dielectric Strength	No defects.								
			The measured and specifications in the	l observed cha e following tab	aracteristics sh le.	ould satisfy the					
		Appearance	No defects or abno	ormalities.			Fix the capac	tor to the supp	orting jig	in the same ma	anner and
		Capacitance Change	Within ±2.5% or ± (whichever is large	:0.25pF er)			Perform the fi listed in the fo	ve cycles acco llowing table.	rding to t	ne four heat tre	eatments
15	Temperature		30pF and over: Q≧	≧1400			Let sit for 24±	2 hours at roo	m temper	ature, then me	asure.
	Cycle	Q	30pF and below: Q	Q≧800+20C			Step	1 Min Operating	2 Room	3 Max Operating	4 Room
			C: Nominal Capaci	itance (pF)			Temp. (°C)	Temp. +0/-3	Temp.	Temp. +3/-0	Temp.
		I.R.	More than 10,000M	MΩ			Time (min.)	30±3	2 to 3	30±3	2 to 3
		Dielectric Strength	No defects.								
			The measured and specifications in the	l observed cha e following tab	aracteristics sh	ould satisfy the					
		Appearance	No defects or abno	ormalities.							
	Humidity	Capacitance Change	Within $\pm 5\%$ or ± 0.1 (whichever is large	5pF er)			Set the capac	itor at 40±2℃ a	and in 90	to 95% humidi	ity for
16	Steady State	Q	30pF and over: Q≧ 10pF and over, 30p 10pF and below: Q	≧350 pF and below: 2≧200+10C	Q≧275+5C/2		Remove and measure.	 set for 24±2 ho	ours at ro	om temperatur	e, then
			C. Nominal Canaci	itanco (nE)							
							_				



GQM Series Specifications and Test Methods

Nominal Values

(ppm/°C)*1

0±30

*1: Nominal values denote the temperature coefficient within a range of 25 to 125°C.

Continued from the preceding page.

For Gene GRM Seri

Table A

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No.	Item		Specifications	Test Method
17			The measured and observed characteristics should satisfy the specifications in the following table.	
	Humidity Load	Appearance	No defects or abnormalities.	Apply the rated voltage at 40 ± 2 °C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature then measure. The charge/discharge current is less than 50mA.
		Capacitance Change	Within ±7.5% or ±0.75pF (whichever is larger)	
		Q	30pF and over: Q≧200 30pF and below: Q≧100+10C/3	
			C: Nominal Capacitance (pF)	
		I.R.	More than $500M\Omega$	
18			The measured and observed characteristics should satisfy the specifications in the following table.	
	High Temperature Load	Appearance	No defects or abnormalities.	Apply 200%* of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Set for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. *GQM22: 150% of the rated voltage
		Capacitance Change	Within $\pm 3\%$ or ± 0.3 pF (whichever is larger)	
		Q	30pF and over: Q≧350 10pF and over, 30pF and below: Q≧275+5C/2 10pF and below: Q≧200+10C	
			C: Nominal Capacitance (pF)	
		I.R.	More than 1,000MΩ	

-55°C

Min.

-0.24

Max.

0.58

Capacitance Change from 25°C (%)

-30°C

Min.

-0.17

Max.

0.40

-10°C

Min.

-0.11

Max.

0.25

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GQM Series Data

Q - Frequency Characteristics



Resonant Frequency - Capacitance



